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INFORMATION BIGGI COURT	Filing Date		2003-10-02	
INFORMATION DISCLOSURE	First Named Inventor Yosh		iyuki Abe	
STATEMENT BY APPLICANT (Not for submission under 37 CFR 1.99)	Art Unit		1796	
(Not for Submission under 67 of it 1.55)	Examiner Name Ma		T. Kopec	
	Attorney Docket Number	er	KAM 20.660	

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/MK/	4	0793277	EP		1997-09-03	CANON KABUSHIKI KAISHA			
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/MK/	6	19654717	DE		1997-07-03	SAMSUNG DISPLAY DEVICE CO LTD			
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/MK/	1	R. GROTH, "Investigation of semiconductor indium oxide Films",1966, pg(s) 69-75, Phsyica Status Solidi, Philips Zentrallaboratorium GmbH, Aachen, Germany(without translation)							
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